

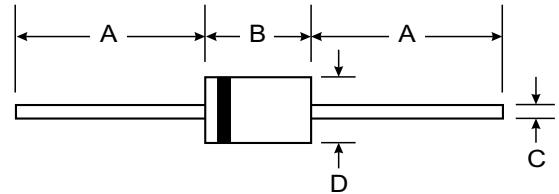
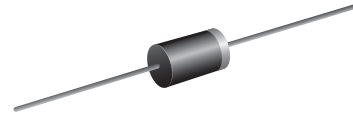
VOLTAGE RANGE: 150-200V
CURRENT: 3.0 A

Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- High Current Capability
- Low Power Loss, High Efficiency
- High Surge Current Capability
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications

Mechanical Data

- Case: DO-201AD, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 1.2 grams (approx.)
- Mounting Position: Any
- Marking: Type Number



DO-201AD		
Dim	Min	Max
A	25.40	—
B	7.20	9.50
C	1.20	1.30
D	4.80	5.30
All Dimensions in mm		



Maximum Ratings and Electrical Characteristics T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Number	SYMBOLS	SB3150	SB3200	UNITS
Maximum repetitive peak reverse voltage	V _{RRM}	150	200	VOLTS
Maximum RMS voltage	V _{RMS}	105	140	VOLTS
Maximum DC blocking voltage	V _{DC}	150	200	VOLTS
Maximum average forward rectified current 0.375" (9.5mm) lead length(see fig.1)	I <sub(av)< sub=""></sub(av)<>	3.0		Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	80.0		Amps
Maximum instantaneous forward voltage at 3.0A	V _F	0.95		Volts
Maximum DC reverse current T _A =25°C at rated DC blocking voltage T _A =100°C	I _R	0.2 2.0		mA
Typical junction capacitance (NOTE 1)	C _J	160		pF
Typical thermal resistance (NOTE 2)	R _{θJA}	40.0		°C/W
Operating junction temperature range	T _J	-65 to +150		°C
Storage temperature range	T _{STG}	-65 to +150		°C

Note:1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted